#### 13.8mm (0.54 INCH) 14 SEGMENT DUAL DIGIT ALPHANUMERIC DISPLAY

Part Number: PDC54-12SYKWA

Super Bright Yellow

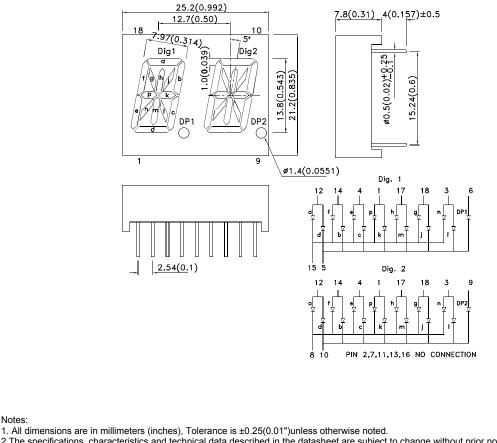
#### **Features**

- 0.54 inch character height.
- Low current operation.
- High contrast and light output.
- Easy mounting on P.C. boards or sockets.
- Categorized for luminous intensity.
- Mechanically rugged.
- Standard: gray face, white segment.
- RoHS compliant.

#### Description

The Super Bright Yellow device is made with AlGaInP (on GaAs substrate) light emitting diode chip.

### Package Dimensions& Internal Circuit Diagram



2. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.

Notes:

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	Selection Guide											
	Part No.	Dice	Lens Type	lv (ucd) [1] @ 10mA		Description						
				Min.	Тур.							
	PDC54-12SYKWA	Super Bright Yellow (AlGaInP)	White Diffused	31000	87000	Common Cathode, Rt. Hand Decimal						
				*14000	*29000							

Note: 1. Luminous intensity/ luminous Flux: +/-15%. \* Luminous intensity value is traceable to the CIE127-2007 compliant national standards.

#### Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Super Bright Yellow	590		nm	I⊧=20mA
λD [1]	Dominant Wavelength	Super Bright Yellow	590		nm	I⊧=20mA
Δλ1/2	Spectral Line Half-width	Super Bright Yellow	20		nm	I⊧=20mA
С	Capacitance	Super Bright Yellow	20		pF	VF=0V;f=1MHz
Vf [2]	Forward Voltage Per Segment or DP	Super Bright Yellow	2.0	2.5	V	IF=20mA
lr	Reverse Current Per Segment or DP	Super Bright Yellow		10	uA	VR=5V

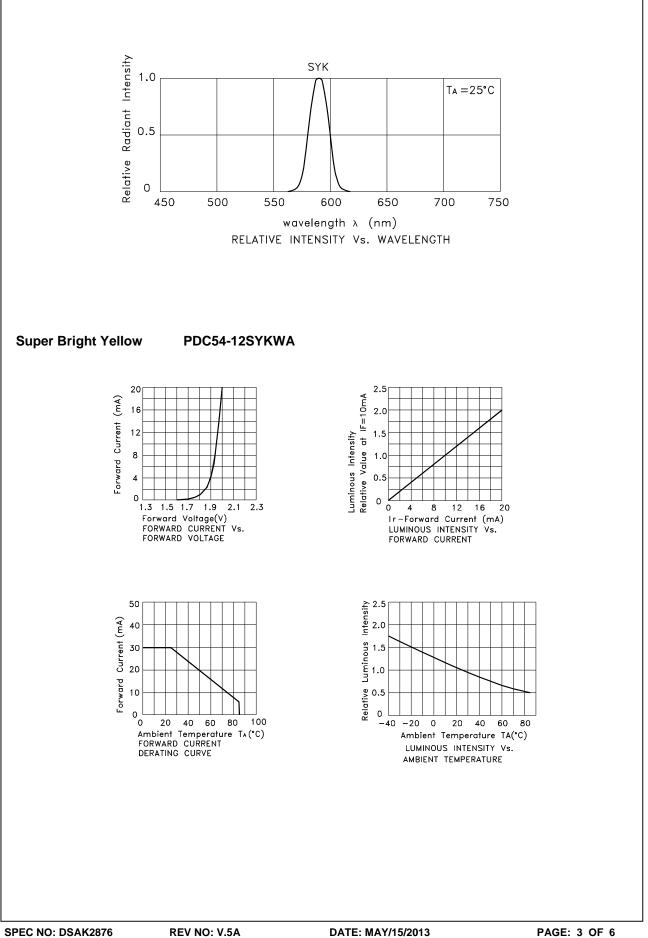
Notes:

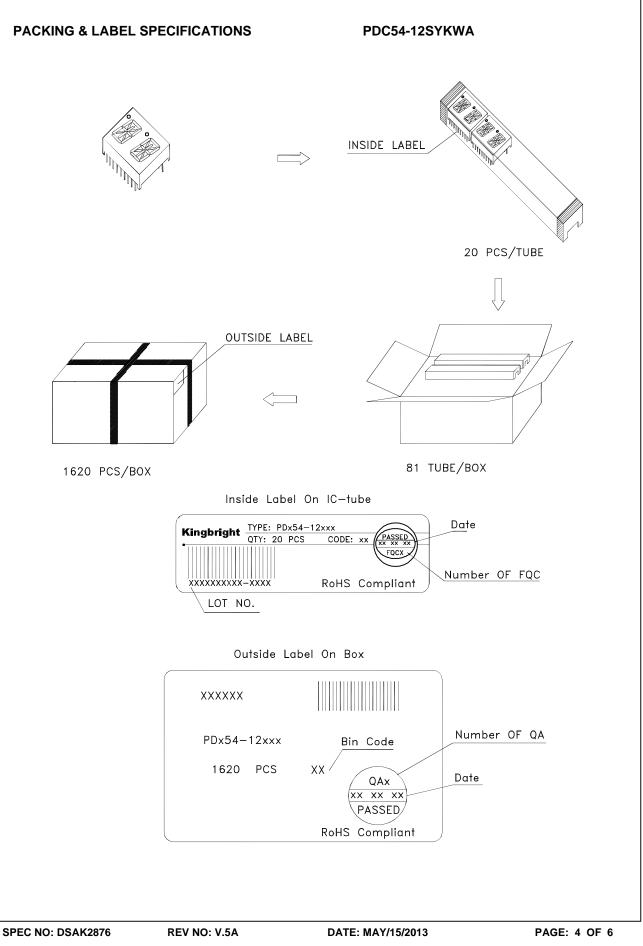
Wavelength: +/-1nm.
Forward Voltage: +/-0.1V.
Wavelength value is traceable to the CIE127-2007 compliant national standards.

#### Absolute Maximum Ratings at TA=25°C

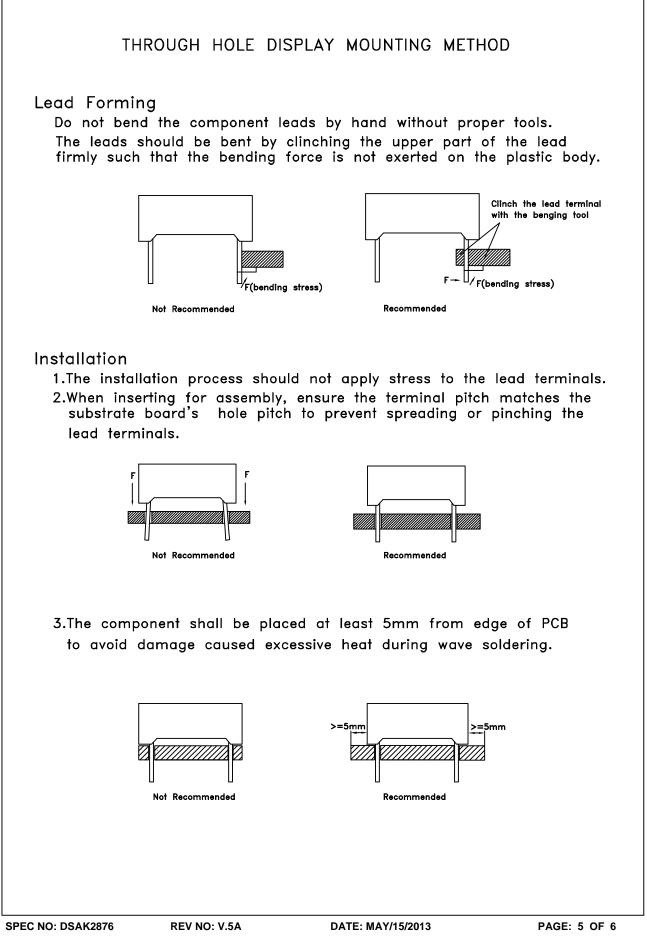
Parameter	Super Bright Yellow	Units			
Power dissipation Per Segment or DP	75	mW			
DC Forward Current Per Segment or DP	30	mA			
Peak Forward Current [1] Per Segment or DP	175	mA			
Reverse Voltage Per Segment or DP	5	V			
Operating / Storage Temperature	-40°C To +85°C				
Lead Solder Temperature[2]	260°C For 3-5 Seconds	260°C For 3-5 Seconds			

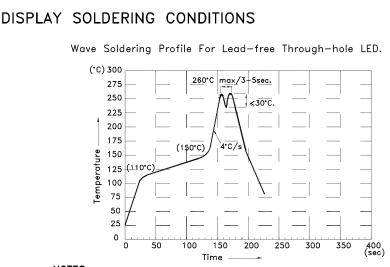
Notes: 1. 1/10 Duty Cycle, 0.1ms Pulse Width. 2. 2mm below package base.





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#### NOTES:

1.Recommend the wave temperature 245°C~260°C.The maximum soldering temperature should be less than 260°C.

2.Do not apply stress on epoxy resins when temperature is over 85°C.

3. The soldering profile apply to the lead free soldering (Sn/Cu/Ag alloy).

4.During wave soldering , the PCB top—surface temperature should be kept below 105°C 5.No more than once.

### Soldering General Notes:

- 1. Through-hole displays are incompatible with reflow soldering.
- 2. If components will undergo multiple soldering processes, or other processes where the components may be subjected to intense heat, please check with Kingbright for compatibility.

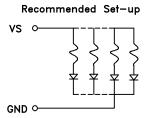
### CLEANING

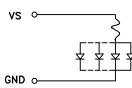
1.Mild "no-clean" fluxes are recommended for use in soldering.

2. If cleaning is required, Kingbright recommends to wash components with water only. Do not use harsh organic solvents for cleaning, because they may damage the plastic parts .And the devices should not be washed for more than one minute.

### CIRCUIT DESIGN NOTES

1.Protective current-limiting resistors may be necessary to operate the Displays.2.LEDs mounted in parallel should each be placed in series with its own current-limiting resistor.





invalid Set-up

Detailed application notes are listed on our website. <u>http://www.kingbright.com/application\_notes</u>

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